



FUKUCOM COMPANY LTD.

福 靈 有 限 公 司

FLAT P, 3/F., EVEREST INDUSTRIAL CENTRE, 396 KWUN TONG ROAD,
KWUN TONG, KOWLOON, HONG KONG.

TEL: 2790-0314 FAX: 2790-0206

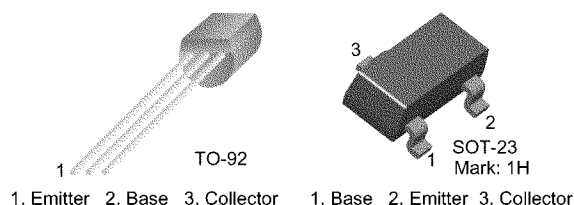
MPSA05/MMBTA05

FAIRCHILD
SEMICONDUCTOR®

MPSA05/MMBTA05

NPN General Purpose Amplifier

- This device is designed for general purpose amplifier applications at collector currents to 300mA.
- Sourced from process 10.



Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	60	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	4.0	V
I_C	Collector current - Continuous	500	mA
T_J, T_{stg}	Junction and Storage Temperature	-55 ~ +150	$^\circ\text{C}$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
Off Characteristics						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage *	$I_C = 1\text{mA}, I_B = 0$	60			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_C = 100\mu\text{A}, I_C = 0$	4			V
I_{CEO}	Collector Cutoff Current	$V_{CE} = 60\text{V}, I_B = 0$			0.1	μA
I_{CBO}	Emitter Cutoff Current	$V_{CB} = 60\text{V}, I_E = 0$			0.1	μA
On Characteristics						
h_{FE}	DC Current Gain	$I_C = 10\text{mA}, V_{CE} = 1.0\text{V}$ $I_C = 100\text{mA}, V_{CE} = 1.0\text{V}$	100 100			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 100\text{mA}, I_B = 10\text{mA}$			0.25	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = 100\text{mA}, V_{CE} = 1.0\text{V}$			1.2	V
Small Signal Characteristics						
f_T	Current Gain Bandwidth Product	$I_C = 10\text{mA}, V_{CE} = 2\text{V},$ $f = 100\text{MHz}$	100			MHz

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2.0\%$

Thermal Characteristics $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.		Units
		MPSA05	*MMBTA05	
P_D	Total Device Dissipation	625	350	mW
	Derate above 25°C	5	2.8	$\text{mW}/^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	$^\circ\text{C}/\text{W}$

* Device mounted on FR-4 PCB $1.6'' \times 0.06''$